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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
09/517,705	03/02/2000	Chunlin Liang	042390.P5771D	4202
75	90 11/20/2002			
Blakely Sokoloff Taylor & Zafman LLP			EXAMINER	
12400 Wilshire Boulevard 7th Floor Los Angeles, CA 90025			LOKE, STEVEN HO YIN	
	 ./		ART UNIT	PAPER NUMBER
•			2811	
			DATE MAILED: 11/20/2003	,

DATE MAILED: 11/20/2002

Please find below and/or attached an Office communication concerning this application or proceeding.

		LA Varaktara Na	(hu				
		Application No.	Applicant(s)				
_		09/517,705	LIANG ET AL.				
(Office Action Summary	Examiner	Art Unit				
		Steven Loke	2811				
The MAILING DATE of this communication appears on the cover sheet with the correspondence address Period for Reply							
THE MAIL - Extensions after SIX (6 - If the period - If NO period - Failure to re - Any reply re	ENED STATUTORY PERIOD FOR REPLY ING DATE OF THIS COMMUNICATION. of time may be available under the provisions of 37 CFR 1.13 (i) MONTHS from the mailing date of this communication. In the or reply specified above is less than thirty (30) days, a reply of for reply is specified above, the maximum statutory period we ply within the set or extended period for reply will, by statute, eceived by the Office later than three months after the mailing ent term adjustment. See 37 CFR 1.704(b).	36(a). In no event, however, may a reply be within the statutory minimum of thirty (30) drill apply and will expire SIX (6) MONTHS frocause the application to become ABANDOI	timely filed lays will be considered timely. om the mailing date of this communication. NED (35 U.S.C. § 133).				
1)⊠ Re	esponsive to communication(s) filed on 26 A	<u> August 2002</u> .					
2a)⊠ Th	is action is FINAL . 2b) ☐ Th	is action is non-final.					
3) Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under <i>Ex parte Quayle</i> , 1935 C.D. 11, 453 O.G. 213.							
Disposition of							
	im(s) <u>1,2,16 and 17</u> is/are pending in the a						
4a) (4a) Of the above claim(s) is/are withdrawn from consideration.						
-	Claim(s) is/are allowed.						
6)⊠ Cla	6)⊠ Claim(s) <u>1, 2, 16, 17</u> is/are rejected.						
7)∐ Cla	Claim(s) is/are objected to.						
8)☐ Cla Application I	im(s) are subject to restriction and/o Papers	r election requirement.					
9) <u></u> The	specification is objected to by the Examine	r.					
10) ☐ The drawing(s) filed on is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.							
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).							
11) ☐ The proposed drawing correction filed on is: a) ☐ approved b) ☐ disapproved by the Examiner.							
If approved, corrected drawings are required in reply to this Office action.							
12)☐ The oath or declaration is objected to by the Examiner.							
Priority under 35 U.S.C. §§ 119 and 120							
13) Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).							
a) ☐ All b) ☐ Some * c) ☐ None of:							
1.[1. Certified copies of the priority documents have been received.						
2.	2. Certified copies of the priority documents have been received in Application No						
	 3. Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)). * See the attached detailed Office action for a list of the certified copies not received. 						
14) Acknowledgment is made of a claim for domestic priority under 35 U.S.C. § 119(e) (to a provisional application).							
a) ☐ The translation of the foreign language provisional application has been received. 15)☐ Acknowledgment is made of a claim for domestic priority under 35 U.S.C. §§ 120 and/or 121.							
Attachment(s)							
1) Notice of I	References Cited (PTO-892) Draftsperson's Patent Drawing Review (PTO-948) on Disclosure Statement(s) (PTO-1449) Paper No(s)	5) Notice of Inform	nary (PTO-413) Paper No(s) nal Patent Application (PTO-152)				
J.S. Patent and Tradem PTO-326 (Rev. 04		ction Summary	Part of Paper No. 13				

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1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

2. Claims 1, 2 and 16 are rejected under 35 U.S.C. 102(b) as being clearly anticipated by Dash et al.

In regards to claim 1, Dash et al. shows all the elements of the claimed invention in fig. 9. It is a circuit device comprising: a first transistor (NMOS) including a first metal gate electrode (a portion of layer [56] formed above the channel region [52]) made of aluminum over a first gate dielectric [14'] on a first area (p-type region [52]) of a semiconductor substrate and having a work function (4.1 eV) corresponding to the work function of the N-type silicon; and a second transistor (PMOS) complementary to the first transistor including a second metal gate electrode [50] made of platinum silicide over a second gate dielectric [14"] on a second different area (n-type region [54]) of a semiconductor substrate and having a work function (5.7 eV) corresponding to the work function of the P-type silicon; and wherein the first metal gate electrode (a portion of layer [56] formed above the channel region [52]) and the second metal gate electrode [50] are not in direct physical contact with each other and are each separately disposed in respective ones of the first area (p-type region [52]) and the second area (n-type region [54]) of the semiconductor substrate.

In regards to claim 2, Dash et al. discloses the first metal gate electrode [56] (aluminum) is a pure metal.

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In regards to claim 16, Dash et al. discloses the first gate dielectric [14'] is silicon dioxide.

- 3. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 4. Claim 17 is rejected under 35 U.S.C. 103(a) as being unpatentable over Dash et al.

In regards to claim 17, it would have been obvious for the first metal gate electrode is one of tantalum, tantalum nitride, molybdenum silicide, and molybdenum nitride since it has been held to be within the general skill of a worker in the art to select a known material on the basis of its suitability for the intended use as a matter of obvious design choice. In re Leshin, 125 USPQ 416.

5. Applicant's arguments filed 8/26/02 have been fully considered but they are not persuasive.

It is urged, in page 3 of the remarks, that fig. 9 of Dash et al. show the gate electrode 56 and gate electrode 50 of Dash are in direct physical contact with each other. However, as explained in the rejection, the first metal gate electrode (a portion of layer [56] formed above the channel region [52]) and the second metal gate electrode [50] are not in direct physical contact with each other. There is a second portion of metal layer [56] separates the first metal gate electrode (a portion of layer [56] formed

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above the channel region [52]) and the second metal gate electrode [50]. Therefore, claims 1, 2, and 16 are still rejected by Dash et al.

It is urged, in page 4 of the remarks, that Dash et al. never discloses the first metal gate electrode and the second metal gate electrode are not in direct physical contact with each other. However, as explained in the previous paragraph, Dash et al. do show the first metal gate electrode and the second metal gate electrode are not in direct physical contact with each other. Therefore, claim 17 is still rejected by Dash et al.

6. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the mailing date of this final action.

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Steven Loke whose telephone number is (703) 308-4920. The examiner can normally be reached on 7:50 am to 5:20 pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Tom Thomas can be reached on (703) 308-2772. The fax phone numbers

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for the organization where this application or proceeding is assigned are (703) 308-7722 for regular communications and (703) 308-7722 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or proceeding should be directed to the receptionist whose telephone number is (703) 308-0956.

sl November 15, 2002 Steven Loke